



High Side Switch ICs 2ch

BD651xF Series

BD20xxAFJ Series

General Description

This High side switch IC for Universal Serial Bus (USB) is a high side switch that features over current protection used in power supply line of USB. Its switch unit has two channels of N-channel power MOSFET which are capable of current equal to 500mA for each channel. Moreover, it features over current detection, thermal shutdown, under voltage lockout and soft start circuit that are all built in.

Features

- Dual N-MOS high side switch
- Continuous current load 0.5A
- Control input logic
 - Active-Low
- Active-High ■ Soft start circuit
- Over current detection
- Over current detect
 Thermal shutdown
- Under voltage lockout
- Open drain error flag output
- Reverse-current protection when switch off
- Flag output delay filter built in

Applications

USB hub in consumer appliances, Car accessory, PC, PC peripheral equipment, and so on.

Typical Application Circuit

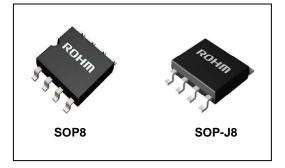
Key Specifications

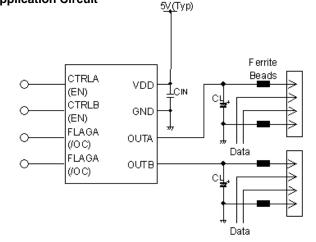
Input voltage range:	
BD651xF Series	3.0V to 5.5V
BD20xxAFJ Series	2.7V to 5.5V
ON resistance :	
BD6512F/BD6513F 1	00mΩ or 120mΩ(Typ.)
BD6516F/BD6517F 1	10mΩ or 140mΩ(Typ.)
BD2042FAFJ/BD2052AFJ	100 mΩ(Typ.)
Over current threshold:	
BD6512F/BD6513F	1.25A min., 2.2A max.
BD6516F/BD6517F	1.2A min., 2.5A max.
BD2042FAFJ/BD2052AFJ	0.7A min., 1.8A max.
Standby current:	
BD20xxAFJ Series	0.01µA (Typ.)
Operating temperature range:	
BD651xF Series	-25°C to +85°C

BD651xF Series -25°C to +85°C BD20xxAFJ Series -40°C to +85°C

Packages

SOP8 SOP-J8 W(Typ.) D(Typ.) H (Max.) 5.00mm x 6.20mm x 1.71mm 4.90mm x 6.00mm x 1.65mm



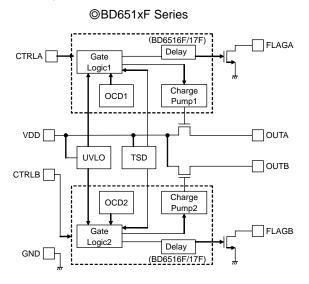


●Lineup

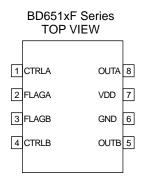
 icup							
Over current threshold			Control innut logic	Da		Onderschle Deut Norschen	
Min.	Тур.	Max.	Control input logic	Pa	ackage	Orderable Part Number	
1.25A	1.65A	2.2A	High			BD6512F – E2	
1.25A	1.65A	2.2A	Low	0000		BD6513F – E2	
1.2A	1.65A	2.5A	High	SOP8		BD6516F – E2	
1.2A	1.65A	2.5A	Low	Reel of 2500		BD6517F – E2	
0.7A	1.0A	1.8A	High	SOP-J8		BD2042AFJ – E2	
0.7A	1.0A	1.8A	Low	30P-J0		BD2052AFJ – E2	

OProduct structure : Silicon monolithic integrated circuit OThis product has no designed protection against radioactive rays

Block Diagrams

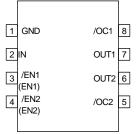


Pin Configurations



OBD20xxAFJ Series TSD1 /EN1 EN1 -___/OC1 Gate Delay Logic1 Charge Pump1 OCD1 IN 🗌 UVLO ۳ /EN2 EN2 Charge OCD2 Pump2 Gate ____/OC2 Logic2 Delay GND TSD2

BD20xxAFJ Series TOP VIEW



OBD20xxAFJ Series

Pin Descriptions

OBD651xF Series

Pin No.	Symbol	1/0	Pin function	Pin. No.	Symbol	1/0	Pin function
1, 4	CTRLA CTRLB	I	Enable input. Switch ON at Low level. (BD6513F/BD6517F) Low level input < 0.7V. Switch ON at High level. (BD6512F/BD6516F) High level input > 2.5V.	1	GND	I	Ground.
2, 3	FLAGA FLAGB	ο	Error flag output. Low at over current, thermal shutdown. Open drain output.	2	IN	I	Power supply input. Input terminal of the switch and power supply of internal circuit.
5, 8	OUTB OUTA	0	Switch output.	3, 4	/EN, EN	I	Enable input. Switch on at Low level. (BD2042AFJ) Low level input < 0.8V Switch On at High level. (BD2052AFJ) High level input > 2.0V
6	GND	I	Ground.	5, 8	/OC	0	Error flag output. Low at over current, thermal shutdown. Open drain output.
7	VDD	Ι	Power supply input. Input terminal of the switch and power supply of internal circuit.	6, 7	OUT	0	Switch output.

Absolute Maximum Ratings

OBD651xF Series

Parameter	Symbol	Ratings	Unit
Input voltage	Vdd	-0.3 to 6.0	V
CTRL voltage	VCTRL	-0.3 to VDD+0.3	V
Flag voltage	V_{FLAG}	-0.3 to 6.0	V
Output voltage	V _{OUT}	-0.3 to VDD+0.3 (BD6512F/ BD6513F)	V
	V 001	-0.3 to 6.0 (BD6516F/ BD6517F)	V
Storage temperature	Tstg	-55 to 150	°C
Power dissipation ^{*1}	Pd	560 ^{*1}	mW

OBD20xxAFJ Series

Parameter	Symbol	Ratings	Unit
Input voltage	Vin	-0.3 to 6.0	V
EN,/EN voltage	Ven, V/en	-0.3 to 6.0	V
/OC voltage	V/oc	-0.3 to 6.0	V
/OC current	IS/oc	10	mA
OUT voltage	Vout	-0.3 to 6.0	V
Storage temperature	Тѕтс	-55 to 150	°C
Power dissipation *1	Pd	560 ^{*1}	mW

*1 This value decreases by 4.48mW/°C above Ta=25°C.

Recommended Operation Ratings

OBD651xF Series

Parameter	Symbol	Ratings	Unit
Input voltage	Vdd	3.0 to 5.5	V
Operation temperature	Topr	-25 to 85	°C
Continuous output current	Ilo	0 to 500	mA

©BD20xxAFJ Series

Parameter	Symbol	Ratings	Unit
Input voltage	Vin	2.7 to 5.5	V
Operation temperature	Topr	-40 to 85	°C
Continuous output current	Ilo	0 to 500	mA

•Electrical Characteristics

Derometer	Parameter Symbol		Unit	Condition		
Falametei	Symbol	Min.	Тур.	Max.	Unit	
Operating current	ldd	-	85	120	μA	VCTRL=5V(BD6512F), 0V(BD6513F) OUT=OPEN
	ססו	-	0.01	2	μA	VCTRL=0V(BD6512F), 5V(BD6513F) OUT=OPEN
Control input voltage	VCTRL	-	-	0.7	V	CTRL Low Level Input
Control input voltage	VCIRL	2.5	-	-	V	CTRL High Level Input
Control input current	ICTRL	-1	0.01	1	μA	VCTRL=0V or 5V
On resistance	Ron	-	100	130	mΩ	VDD=5V,IOUT=500mA
On resistance	KUN	-	120	160	mΩ	VDD=3.3V,IOUT=500mA
Turn on delay	Trd	100	600	2000	μs	RL=10Ω
Turn on rise time	Tr	200	1500	6000	μs	RL=10Ω
Turn off delay	Tfd	-	3	20	μs	RL=10Ω
Turn off fall time	TF	-	1	20	μs	RL=10Ω
UVLO threshold voltage	Vuvloh	2.3	2.5	2.7	V	VDD increasing
OVEO Intestiola voltage	VUVLOL	2.1	2.3	2.5	V	VDD decreasing
Thermal shutdown threshold	TTS	-	135	-	°C	
Flag output resistance	Rflag	-	16	40	Ω	IFLAG=5mA
Flag off current	IFLAG	-	0.01	1	μA	
Current limit threshold	ITHLIM	1.25	1.65	2.20	А	
Over current limit level	ILIM	0.6	1.1	1.6	А	

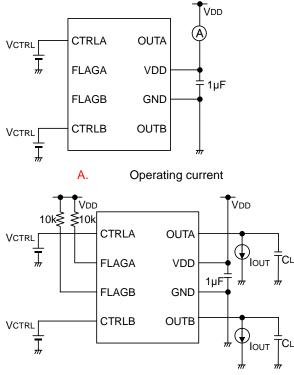
ØBD6516F/BD6517F (V_{DD} =5V, Ta=25°C, unless otherwise specified.)

Parameter	Symbol		Unit	Condition		
Faiamelei	Symbol	Min.	Тур.	Max.	Unit	
Current consumption	1	-	100	140	μA	VCTRL=5V(BD6516F), 0V(BD6517F) OUT=OPEN
Current consumption	IDD	-	0.01	2	μA	VCTRL=0V(BD6516F), 5V(BD6517F) OUT=OPEN
CTRL input voltage	Vctrl	-	-	0.7	V	Low level input voltage
OTTLE input voltage	VOIKE	2.5	-	-	V	High level input voltage
CTRL input current		-1	0.01	1	μA	VCTRL=0V or 5V
FLAG output resistance	R_{FLAG}	-	250	450	Ω	IFLAG=1mA
FLAG output leak current	I _{FLAG}	-	0.01	1	μA	Vflag=5V
FLAG output delay	TDFL	-	1	4	ms	
ON resistance	R _{ON}	-	110	150	mΩ	VDD=5V,IOUT=500mA
ONTESISIANCE		-	140	180	mΩ	VDD=3.3V,IOUT=500mA
Over-current Threshold	Ітн	1.2	1.65	2.5	А	
Short circuit output current	Isc	1.2	1.65	2.2	А	Vout=0V
Output leak current	ILEAK	-	-	10	μA	VCTRL=0V(BD6516F), 5V(BD6517F)
Thermal shutdown threshold	TTS	-	135	-	°C	At Tj increase
Output rise time	TON1	100	1300	4000	μs	RL=10Ω
Output turn on delay time	TON2	200	1500	6000	μs	RL=10Ω
Output fall time	TOFF1	-	1	20	μs	RL=10Ω
Output turn off delay time	TOFF2	-	3	20	μs	RL=10Ω

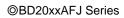
Parameter	Symbol	Limits		- Unit	Condition		
Farameter	Symbol	Min.	Тур.	Max.	Unit	Condition	
Operating Current	IDD	-	110	140	μA	$V_{EN} = 0V$, $OUT = OPEN (BD2042AFJ)$ $V_{EN} = 5V$, $OUT = OPEN (BD2052AFJ)$	
Standby Current	Istb	-	0.01	1	μA	$V_{EN} = 5V$, $OUT = OPEN$ (BD2042AFJ) $V_{EN} = 0V$, $OUT = OPEN$ (BD2052AFJ)	
		2.0	-	-	V	High input	
/EN input voltage	V/en,en	-	-	0.8	V	Low input	
		-	-	0.4	V	Low input 2.7V≤ VIN ≤4.5V	
/EN input current	l/en,en	-1.0	0.01	1.0	μA	V/EN,EN = 0V or V/EN,EN = 5V	
/OC output LOW voltage	V/oc	-	-	0.5	V	I/OC = 5mA	
/OC output leak current	IL/oc	-	0.01	1	μA	V/OC = 5V	
ON resistance	Ron	-	100	130	mΩ	IOUT = 500mA	
Over Current Threshold	Ітн	0.7	1.0	1.8	А		
Output current at short	Isc	0.7	1.0	1.3	А		
Output rise time	TON1	-	1.8	10	ms		
Output turn on time	TON2	-	2.1	20	ms		
Output fall time	TOFF1	-	1	20	μs	RL = 10Ω , CL = OPEN	
Output turn off time	TOFF2	-	3	40	μs		
UVLO threshold	ντυνη	2.1	2.3	2.5	V	Increasing VIN	
	Vtuvl	2.0	2.2	2.4	V	Decreasing VIN	

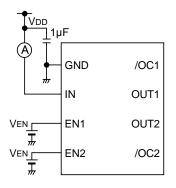
Measurement Circuit

OBD651xF Series

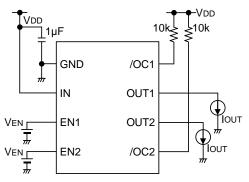


C. ON resistance, Over current detection



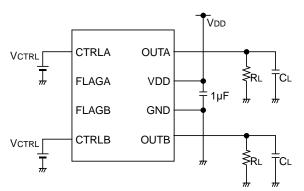


E. Operating current

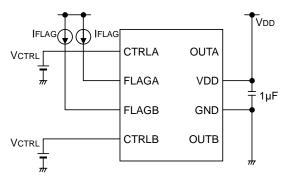


G. ON resistance, Over current detection

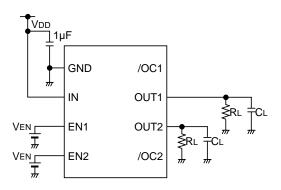




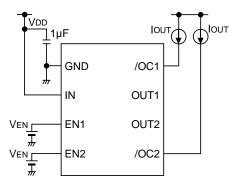
B. CTRL input voltage, Output rise, fall time



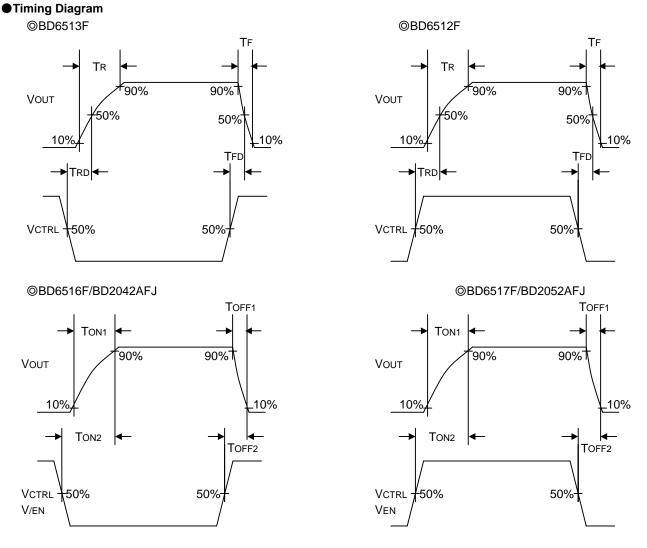
D. FLAG output resistance



F. EN, /EN input voltage, Output rise, fall time



H. /OC output LOW voltage





●Typical Performance Curves ◎BD6512F/ BD6513F

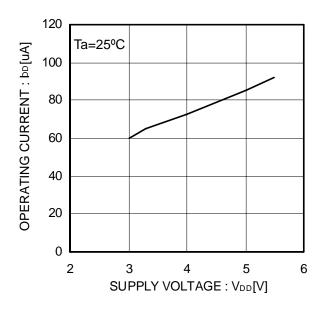
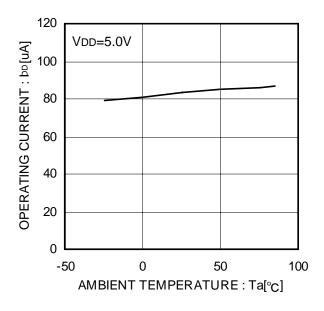
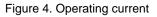


Figure 3. Operating current





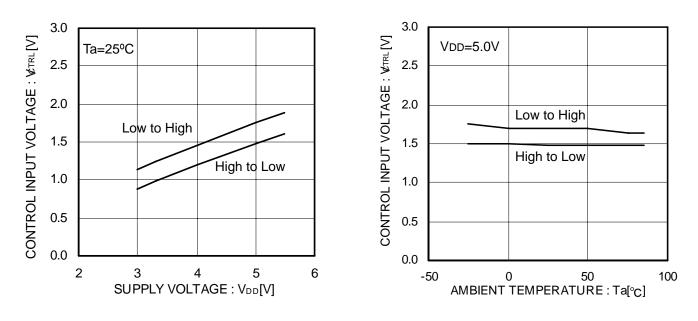
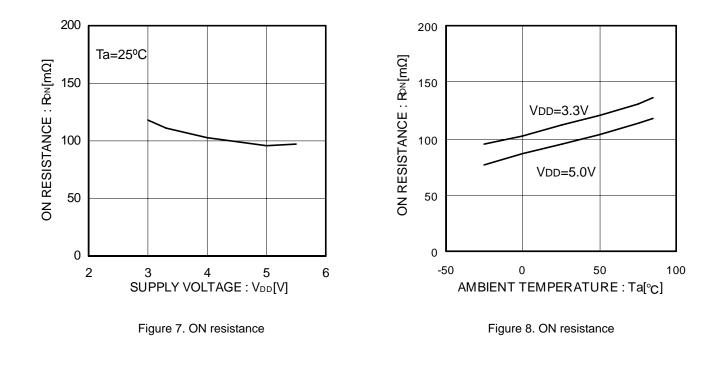


Figure 5. CTRL input voltage

Figure 6. CTRL input voltage



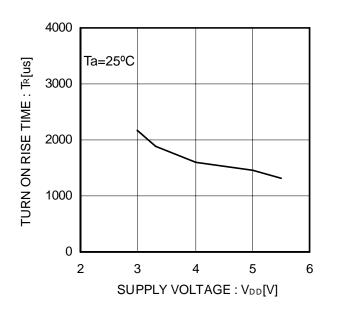
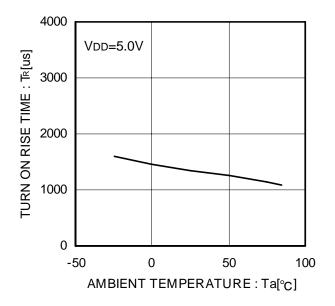
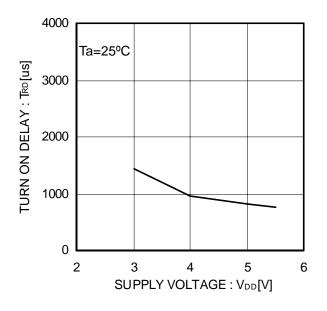
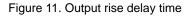


Figure 9. Output rise time









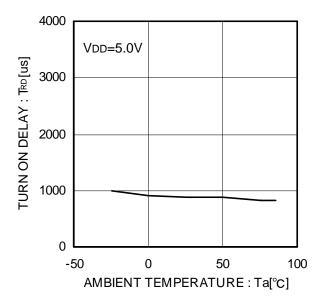


Figure 12. Output rise delay time

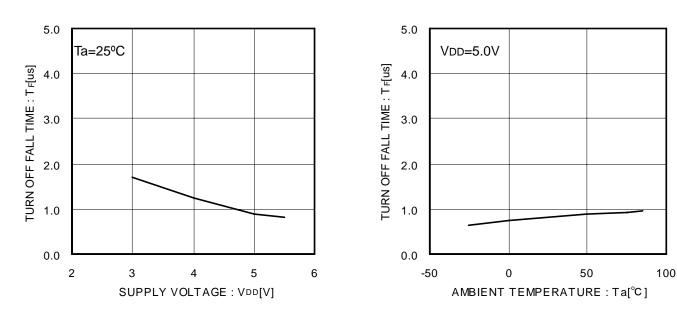
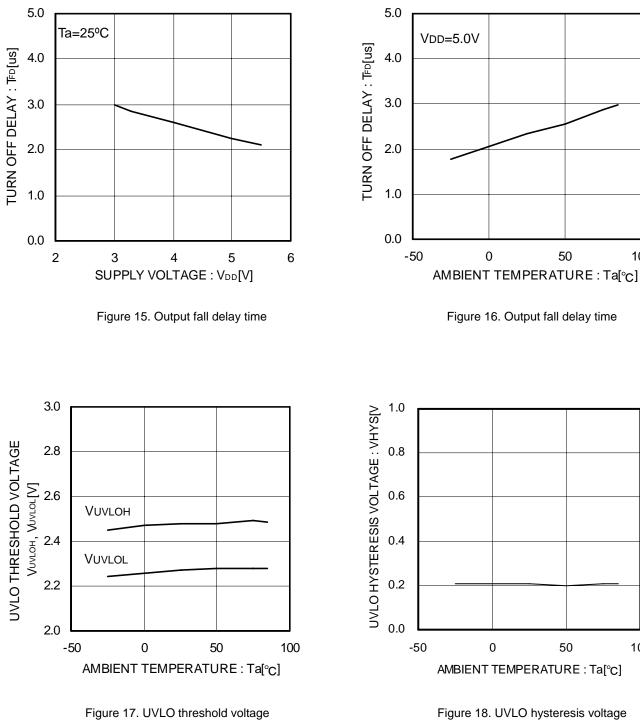


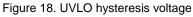
Figure 13. Output fall time



100

100





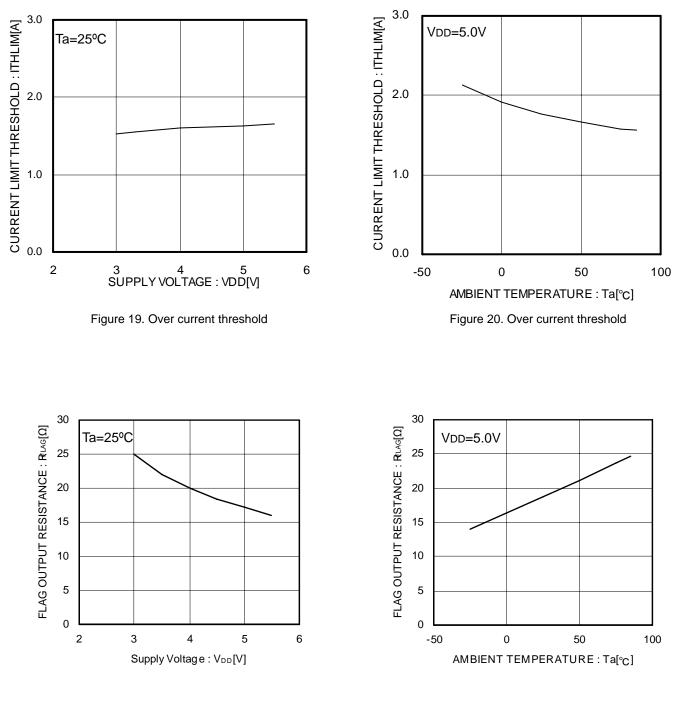
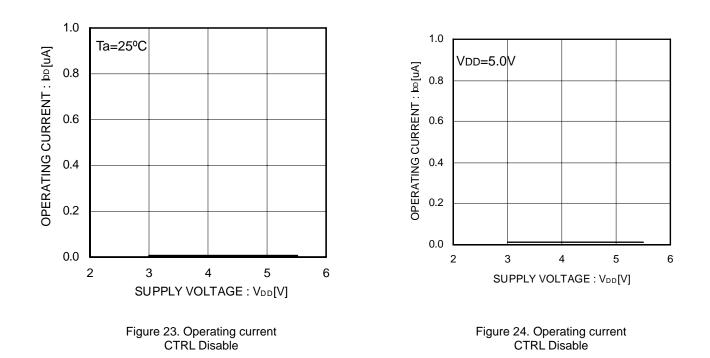
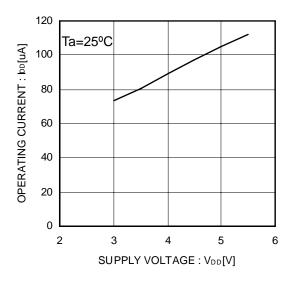


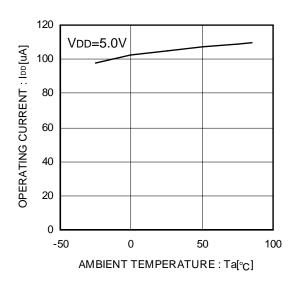
Figure 21. Flag output resistance

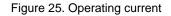
Figure 22. Flag output resistance

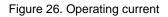


Typical Performance Curves – continued ©BD6516F/ BD6517F









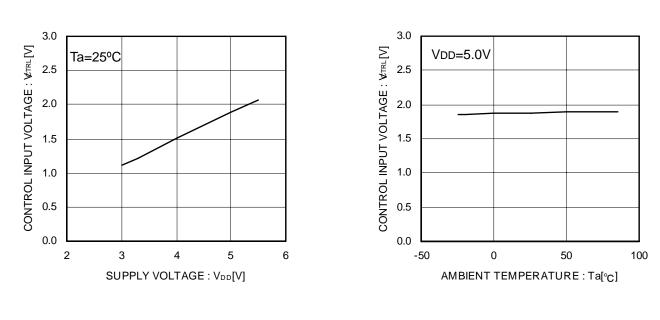


Figure 27. CTRL input voltage (BD6516F) Figure 28. CTRL input voltage (BD6516F)

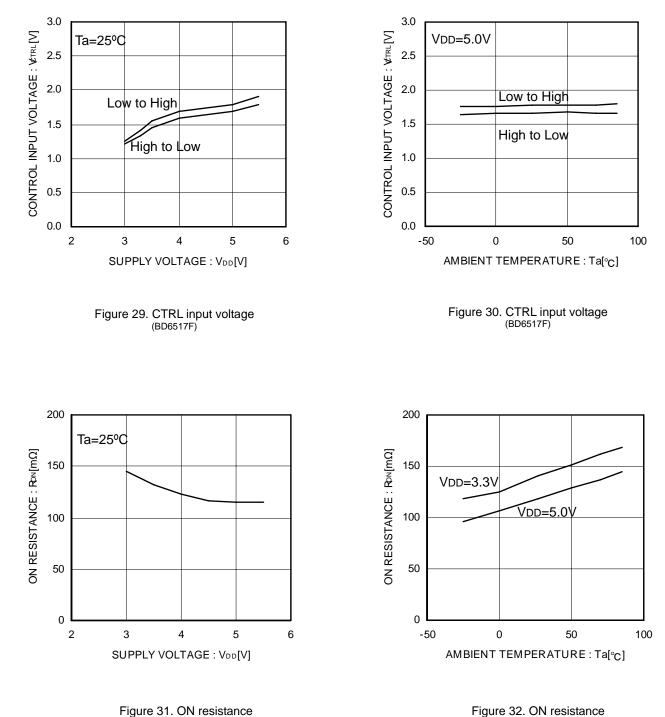


Figure 32. ON resistance

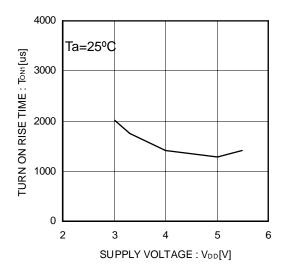


Figure 33. Output rise time

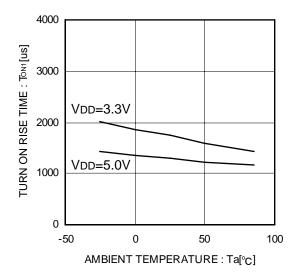


Figure 34. Output rise time

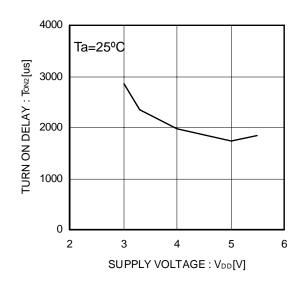


Figure 35. Output rise delay time

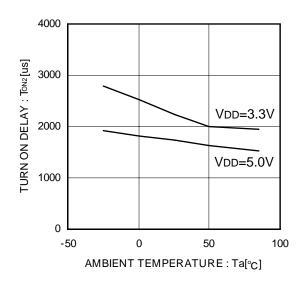


Figure 36. Output rise delay time

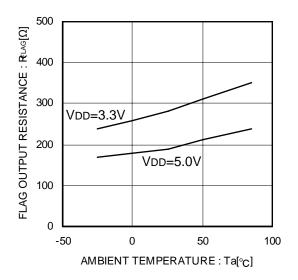


Figure 37. Flag output resistance

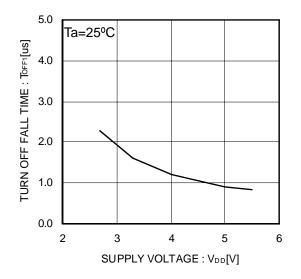
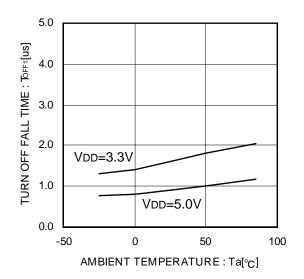


Figure 38. Output fall time





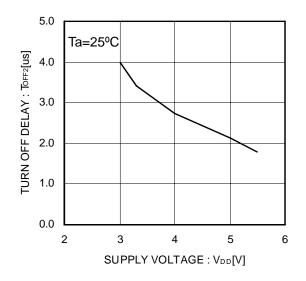


Figure 40. Output fall delay time

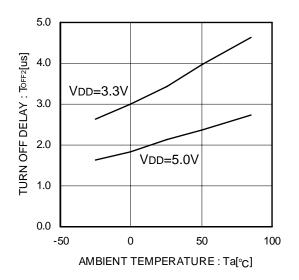


Figure 41. Output fall delay time

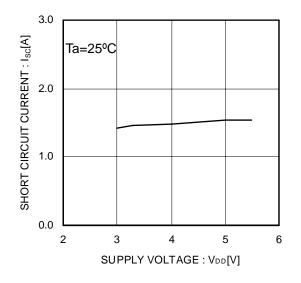


Figure 42. Short-circuit output current

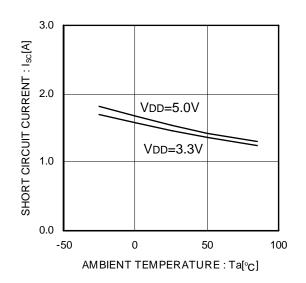


Figure 43. Short-circuit output current

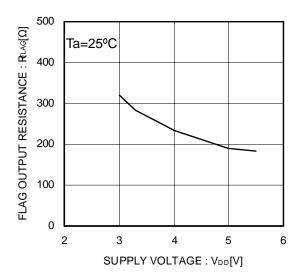


Figure 44. Flag output resistance

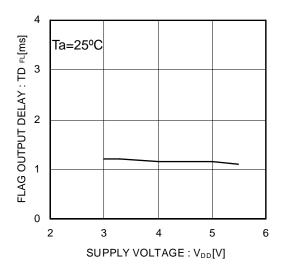


Figure 45. Flag output delay

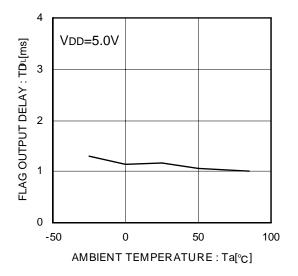
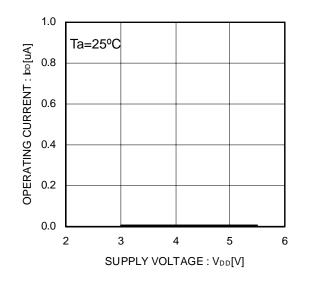
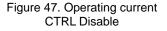


Figure 46. Flag output delay





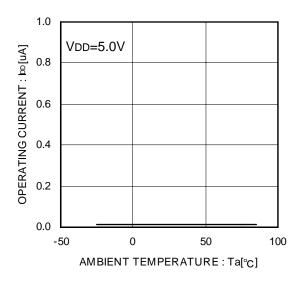
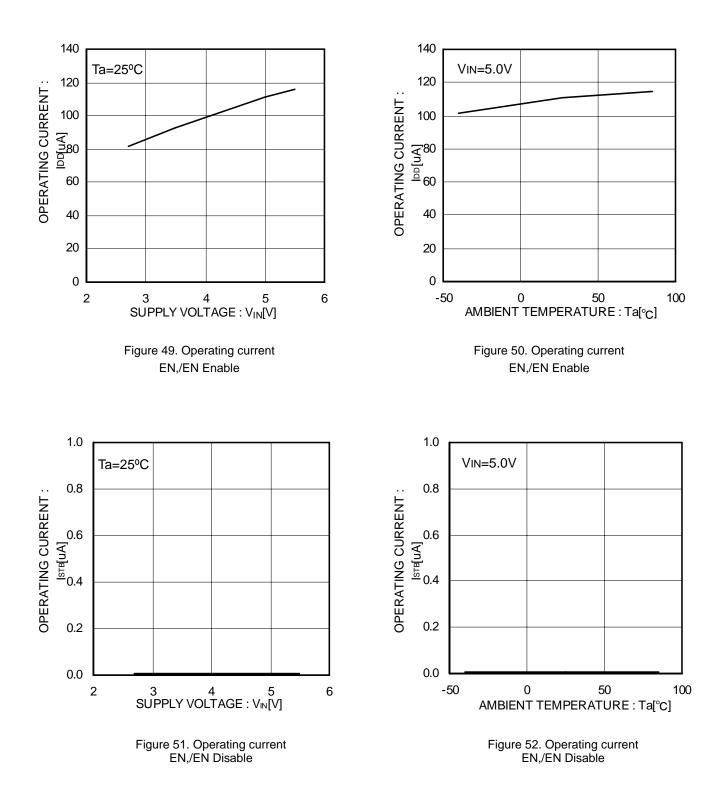
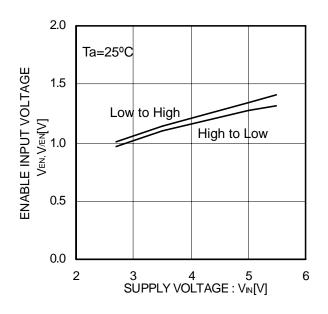
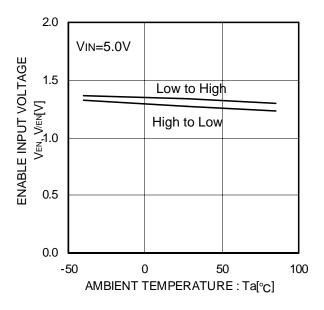


Figure 48. Operating current CTRL Disable











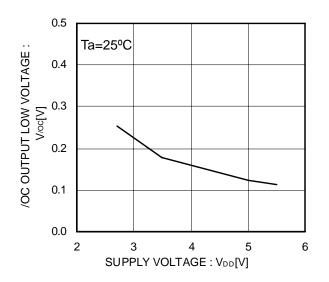


Figure 55. /OC output LOW voltage

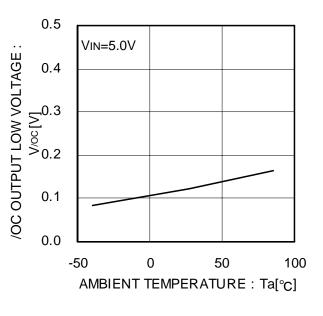


Figure 56. /OC output LOW voltage

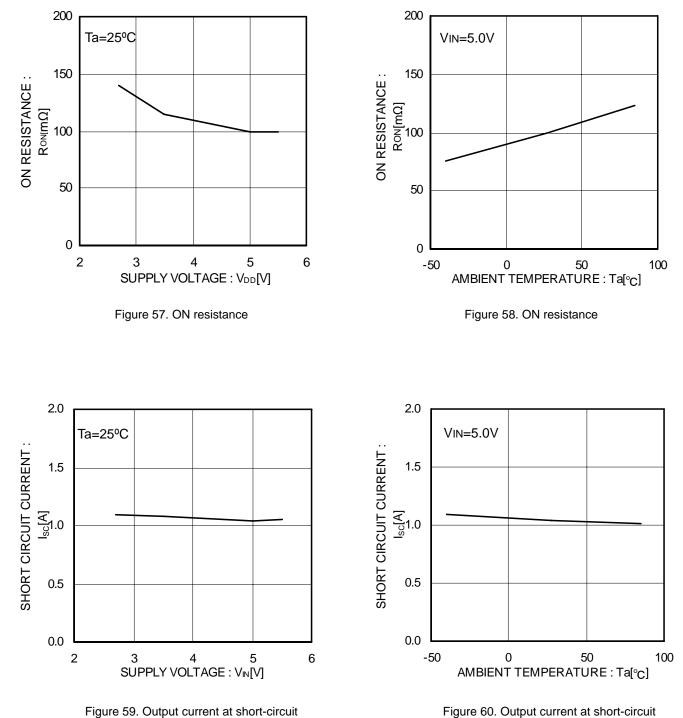
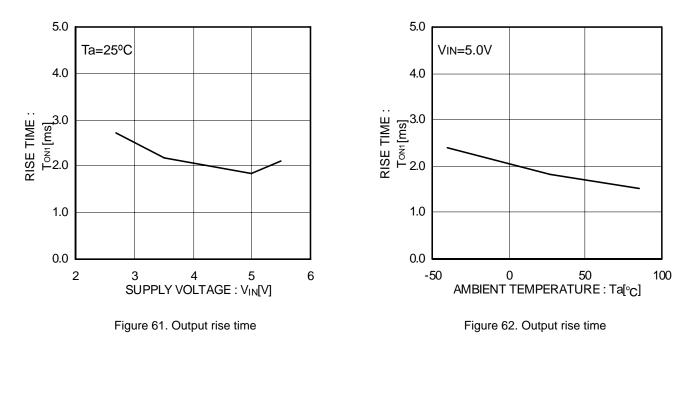
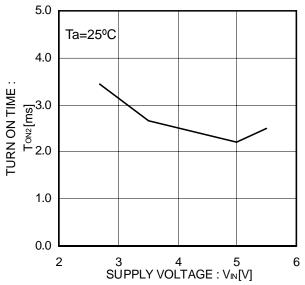
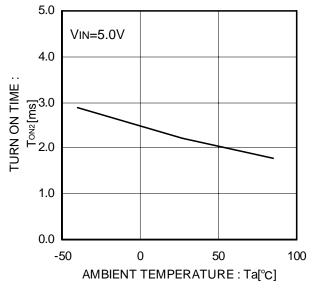


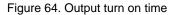
Figure 60. Output current at short-circuit











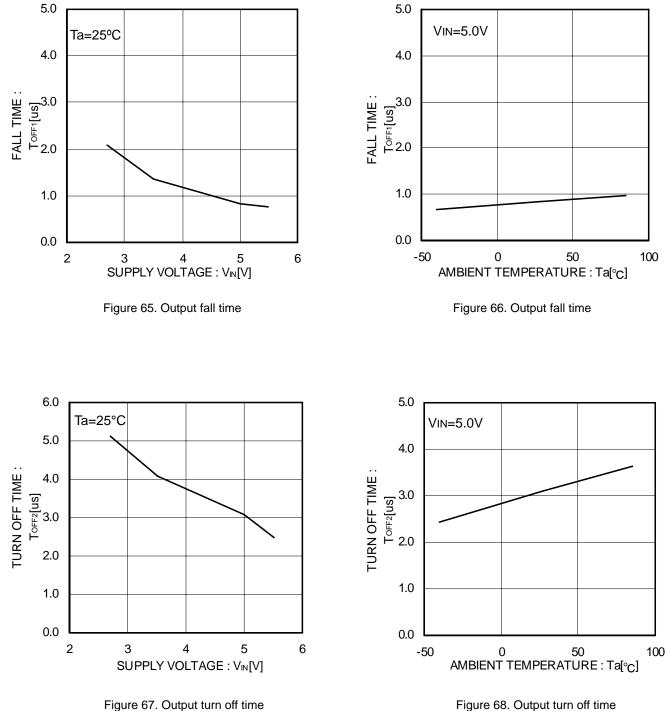
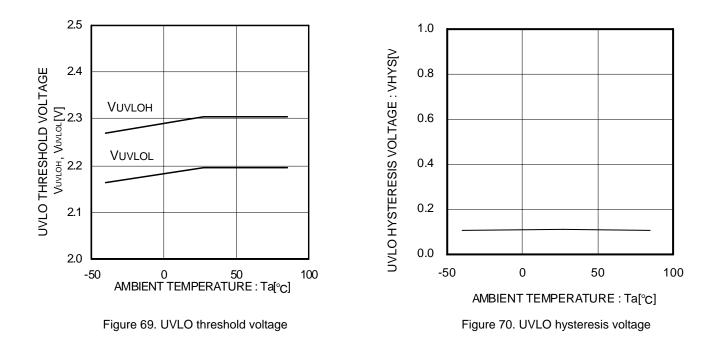
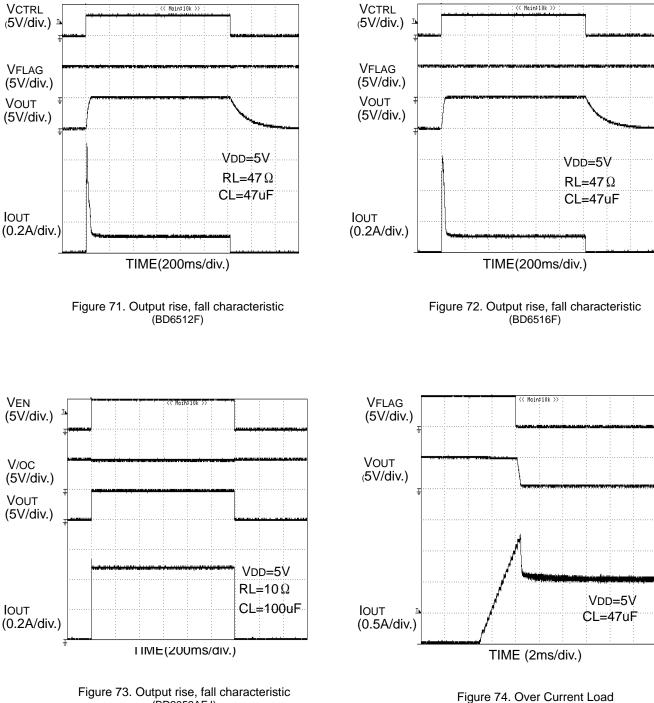


Figure 68. Output turn off time



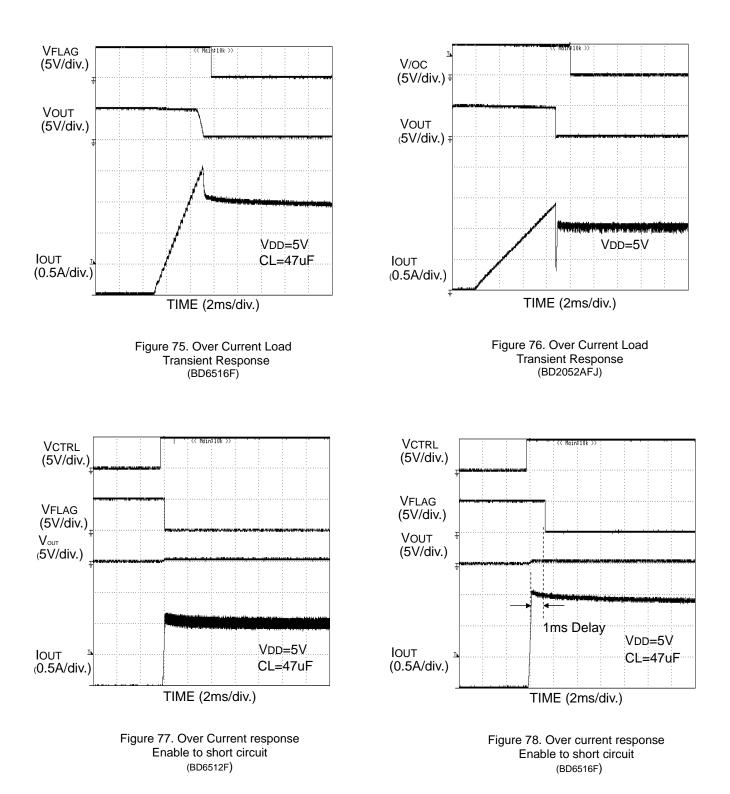
Typical Wave Forms



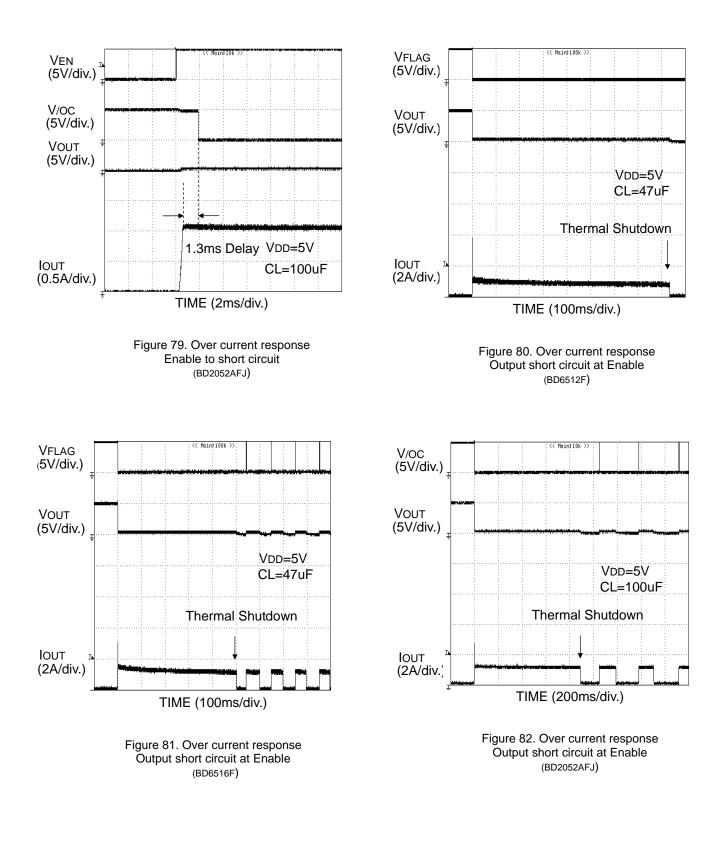
(BD2052AFJ)

Transient Response (BD6512F)

Typical Wave Forms - continued

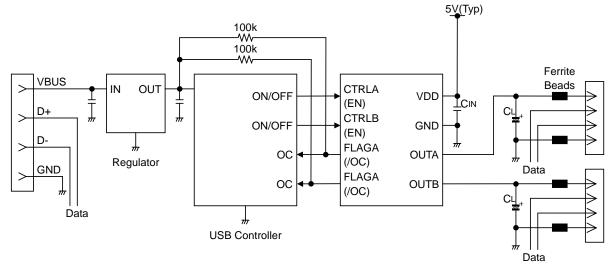


Typical Wave Forms - continued



Regarding the output rise/fall and over current detection characteristics of BD6513F, BD6517F, BD2042AFJ refer to the characteristic of BD6512F, BD2052AFJ.

•Typical Application Circuit



Application Information

Excessive current flow due to output short circuit or ringing caused by the inductance from supply line of IC can cause IC malfunction during operation. To avoid this case, connect a bypass capacitor to VDD pin and GND pin of IC. 1uF or higher is recommended.

Pull up flag output by resistance of $10k\Omega$ to $100k\Omega$.

Set up value which satisfies the application as CL and Ferrite Beads.

The system connection diagram doesn't guarantee operation as the application.

The external circuit constant values can be changed and should be used with adequate margins by taking into account its external parts, or behavior of IC must include not only static characteristics but also transient characteristics.

In BD6512F/BD6513F, there are cases where over current detection error flags its output by inrush current at switch on or when supplying the active line of peripheral devices. In the case of erroneous detection in BD6512F/BD6513F, use RC filter shown in Figure 83 for FLAG output.

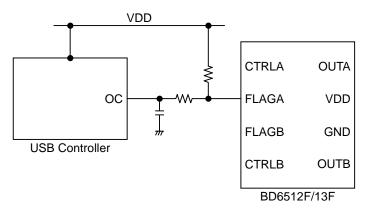


Figure 83. FLAG output RC filter

Functional Description

1. Switch operation

VDD(IN) pin and OUT pin are connected to the drain and the source of switch MOSFET respectively. And the VDD(IN) pin is used also as power source of internal control circuit.

When the switch is turned on from CTRL(EN) control input, VDD(IN) and OUT are connected. In a normal condition, current flows from VDD to OUT. If the voltage at OUT is higher than VDD, current flows from OUT to VDD, since the switch is bidirectional.

©BD6512F/ BD6513F

There is a parasitic diode between the drain and the source of switch MOSFET. Therefore, even when the switch is off, if the voltage of OUT is higher than that of VDD, current flows from OUT to VDD.

©BD6516F/BD6517F/BD2042AFJ/BD2052AFJ

There is no parasitic diode and it is possible to prevent current from flowing reversely from OUT to VDD.

2. Thermal shutdown (TSD)

Thermal shut down circuit turns off the switch and outputs an error flag when the junction temperature in the chip exceeds a threshold temperature. The thermal shut down circuit works when either of two control signals is active. In BD6512F/BD6513F/BD6516F/BD6517F, the switches of both OUTA and OUTB turn off and output an error flags;. BD2042AFJ/BD2052AFJ have dual threshold temperature for its thermal shutdown. Since thermal shutdown works at a lower junction temperature , only the switch of an overcurrent state become off whenever over current occurs and outputs an error flag. @BD6512F/BD6513F

If the switch off status of the thermal shut down is latched switch off and error flag output status are maintained even when the junction temperature decreases. To release the latch, it is necessary to input a signal to switch off by CTRL pin or set UVLO state. When the input signal is turned on or UVLO is released, the switch on status and error flag output resets.

©BD6516F/BD6517F/BD2042AFJ/BD2052AFJ

Thermal shut down detection has hysteresis. Therefore, when the junction temperature goes down, switch on and error flag output automatically reset However, until output short circuit is removed or the switch is turned off causing junction temperature to increase, thermal shut down detection and recovery are repeated.

3. Over current detection/limit circuit

The over current detection circuit limits current and outputs error flag when current flowing in each switch MOSFET exceeds a specified value. There are three types of response against over current. The over current limit detection circuit works when the switch is ON (CTRL • EN signal is active).

3-1 When the switch is turned ON while the output is in short-circuit status

When the output is in short-circuit status, the switch is set at current limit mode as soon as the switch is turned ON.

3-2 When the output short-circuits while the switch is ON

When the output short-circuits or when large current flows while the switch is ON, the over current limit circuit operates. When the current limit detection circuit works, current limitation is applied.

3-3 When the output current increases gradually

When the output current increases gradually, current limitation does not work until the output current exceeds the over current detection value. When it exceeds the detection value, current limitation is applied.

4. Under voltage lockout (UVLO)

When the supply voltage is below UVLO threshold level, UVLO circuit turns OFF the switch to prevent malfunction. The UVLO circuit works when either of two control signals is active.

OBD6512F/BD6513F

UVLO circuit prevents the switch from turning ON until the VDD exceeds 2.5V(Typ.). If the VDD drops below 2.3V(Typ.) while the switch is ON, then UVLO shuts OFF the switch.

OBD2042AFJ/BD2052AFJ

UVLO circuit prevents the switch from turning on until the VIN exceeds 2.3V(Typ.). If the VIN drops below 2.2V(Typ.) while the switch is ON, then UVLO shuts OFF the switch. UVLO has hysteresis of 100mV(Typ).

5. Error flag output

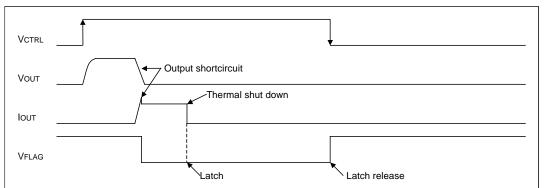
Error flag output is N-MOS open drain output.

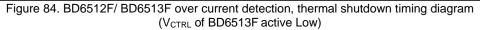
OBD6512F/BD6513F

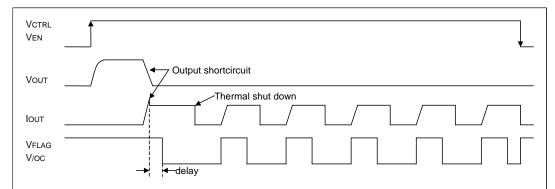
At detection of over current limit, thermal shutdown, and UVLO, it output a low level signal.

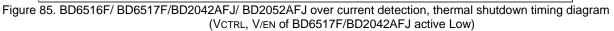
©BD6516F/BD6517F/BD2042AFJ/BD2052AFJ

At detection of over current limit and thermal shutdown, it outputs a low level signal. Error flag output at over current detection has delay filter. This delay filter prevents instantaneous current detection such as inrush current at switch ON, or applying external power supplies.



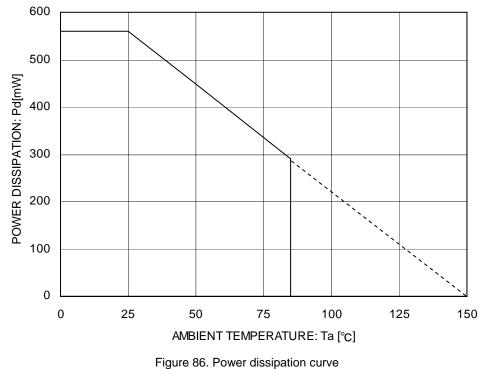






Power Dissipation

(SOP8, SOP-J8)



●I/O Equivalent Circuit

OBD651xF Series

Symbol	Pin No.	Equivalent circuit (BD6512F/ BD6513F)	Equivalent circuit (BD6516F/ BD6517F)
CTRLA CTRLB	1, 4	CTRLA CTRLB CTRLB	CTRLA CTRLB
FLAGA FLAGB	2, 3	FLAGA FLAGB	FLAGA FLAGB
OUTA OUTB	5, 8		

OBD20xxAFJ Series

Symbol	Pin No	Equivalent circuit
/EN1(EN1) /EN2(EN2)	3, 4	/EN1(EN1) /EN2(EN2)
/OC1 /OC2	5, 8	
OUT1 OUT2	6, 7	

Operational Notes

(1) Absolute Maximum Ratings

Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings

(2) Recommended operating conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

(3) Reverse connection of power supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply terminals.

(4) Power supply line

Design the PCB layout pattern to provide low impedance ground and supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

(5) Ground Voltage

The voltage of the ground pin must be the lowest voltage of all pins of the IC at all operating conditions. Ensure that no pins are at a voltage below the ground pin at any time, even during transient condition.

(6) Short between pins and mounting errors

Be careful when mounting the IC on printed circuit boards. The IC may be damaged if it is mounted in a wrong orientation or if pins are shorted together. Short circuit may be caused by conductive particles caught between the pins.

(7) Operation under strong electromagnetic field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

(8) Testing on application boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

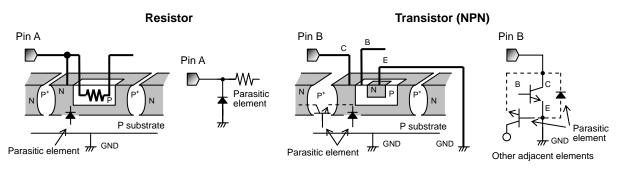
(9) Regarding input pins of the IC

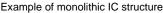
This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode.

When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.





(10) GND wiring pattern

When using both small-signal and large-current GND traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the GND traces of external components do not cause variations on the GND voltage. The power supply and ground lines must be as short and thick as possible to reduce line impedance.

(11) External Capacitor

When using a ceramic capacitor, determine the dielectric constant considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

(12) Thermal shutdown circuit (TSD)

The IC incorporates a built-in thermal shutdown circuit, which is designed to turn off the IC when the internal temperature of the IC reaches a specified value. Do not continue to operate the IC after this function is activated. Do not use the IC in conditions where this function will always be activated.

(13) Thermal consideration

Use a thermal design that allows for a sufficient margin by taking into account the permissible power dissipation (Pd) in actual operating conditions. Consider Pc that does not exceed Pd in actual operating conditions (Pc≥Pd).

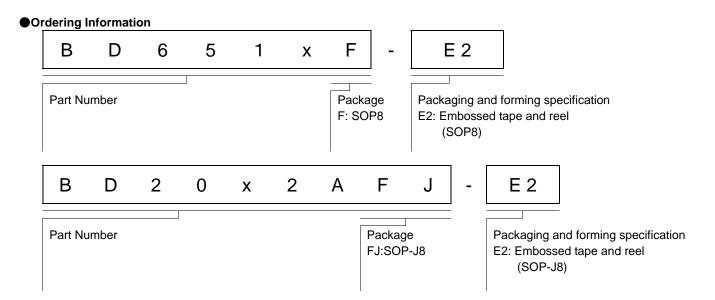
Package Power dissipation	
Power dissipation	

: Pd (W)=(Tjmax−Ta)/ θ ja : Pc (W)=(Vcc−Vo)×lo+Vcc×lb

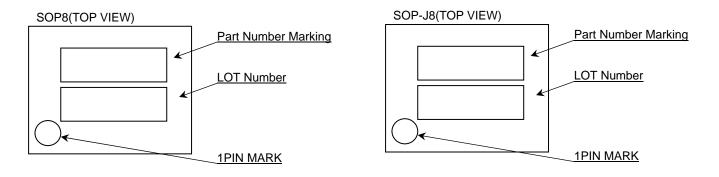
Tjmax : Maximum junction temperature=150°C, Ta : Peripheral temperature[°C],

 θ ja : Thermal resistance of package-ambience[°C/W], Pd : Package Power dissipation [W],

Pc : Power dissipation [W], Vcc : Input Voltage, Vo : Output Voltage, Io : Load, Ib : Bias Current

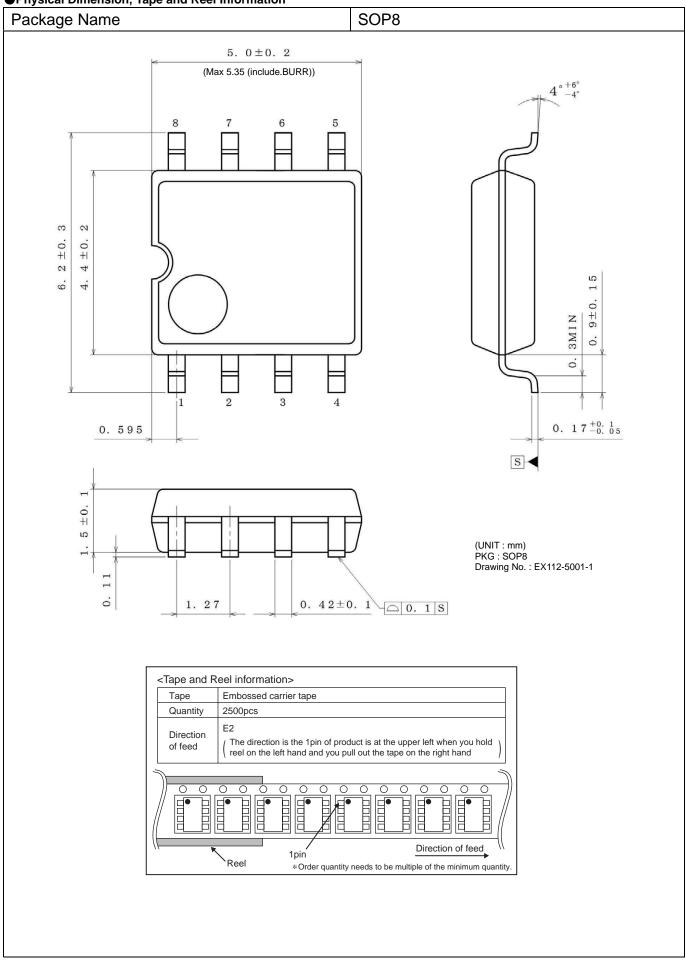


Marking Diagrams

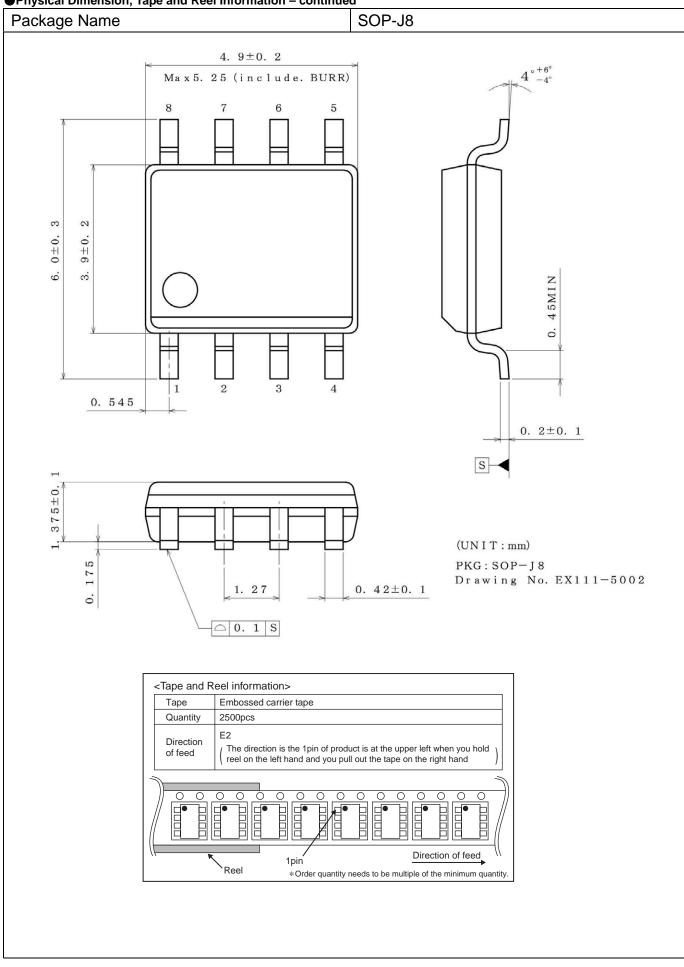


Part Number	Part Number Marking	
BD6512F	BD6512F D6512	
BD6513F	D6513	
BD6516F	D6516	
BD6517F	D6517	
BD2042AFJ	D042A	
BD2052AFJ	D052A	

Physical Dimension, Tape and Reel Information



Physical Dimension, Tape and Reel Information – continued



Revision History

Date	Revision	Changes	
11.Mar.2013	001	New Release	

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CLASSⅣ		CLASSⅢ	CLASSⅢ

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 - [d] the Products are exposed to high Electrostatic
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